

## INTRODUCTION

- $YFeO_3$  : Applications<sup>[1]</sup>:
  - Sensors
  - Solid oxide fuel cells
  - Magneto-optical devices
  - Catalyst (BG = 2,37eV<sup>[2]</sup>)

### •Catalyzed reaction : water splitting

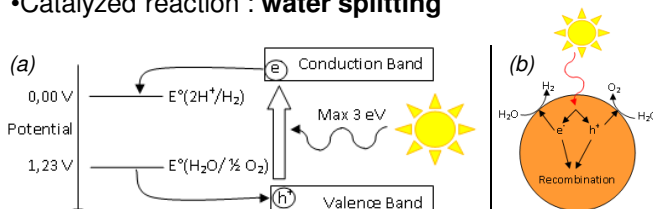


Figure 1: Principles (a) and processes (b) of water splitting using a semiconductor photocatalysts

## TECHNIQUE : Dip-Coating

### Process

- 1) Substrate immersion
- 2) Deposition and removal
- 3) Drain
- 4) Solvent evaporation
- 5) Stabilization

### Parameters

- Substrate
- Dipping/Removal speed
- Relative humidity
- Stabilizing temperature

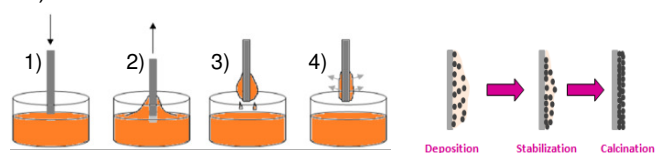


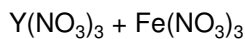
Figure 2: The different stages of the dip-coating method

Figure 3: Particles repartition at different temperatures

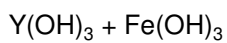
## RESULTS & DISCUSSIONS

### Powders:

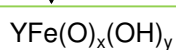
#### Synthesis



(+ chelating agent)  
+  $NH_4OH$



+  $HNO_3$



80 °C, overnight  
Combustion, 2h

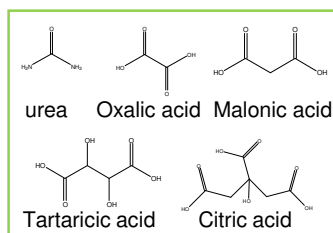


Figure 4: Chelating agent

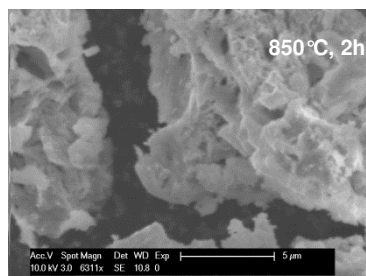
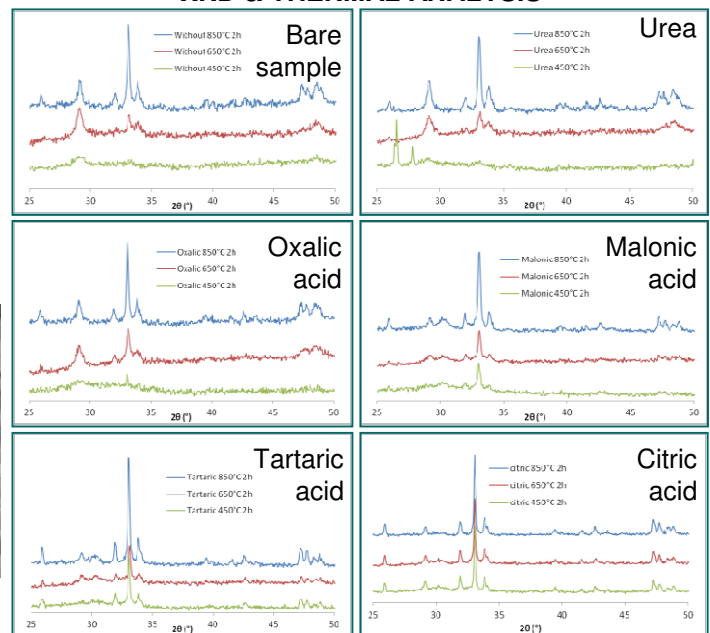


Figure 5: SEM image of  $YFeO_3$  powder calcinated at 850 °C 2h

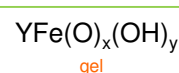
### XRD & THERMAL ANALYSIS



### Thin films

#### Synthesis:

same as powder until



- 1) dip-coating
- 2) calcination

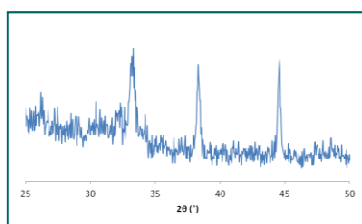


Fig 6: XRD of  $YFeO_3/Si$  calcinated at 850 °C during 10h

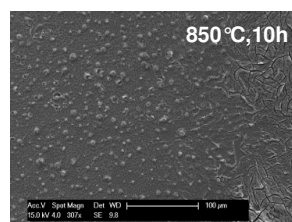


Fig 5: SEM image of calcinated  $YFeO_3/Si$

### Conclusions

✓ Successfully synthesize  $YFeO_3$   
→Crystallization temperature: 850 °C

✓ Successfully crystallize  $YFeO_3$  on monocrystalline Si

At 850 °C, TCO melts...

→ Need to reduce the crystallization temperature

✓ Chelating agent are useful  
→ best one = **Citric acid**



<sup>[1]</sup> Rajendran, M., Ghanashyam Krishna, M., Bhattacharya, A.K., Low temperature preparation of orthoferrite thin-films by an inorganic sol-gel process. *Thin Solid Films* 2001, 385, 230-233.

<sup>[2]</sup> Tang, Peisong; Sun, He; Chen, Haifeng; Cao, Feng, Hydrothermal Processing-Assisted Synthesis of Nanocrystalline  $YFeO_3$  and its Visible-Light Photocatalytic Activity, *Current Nanoscience*, Vol 8, Num 1, Feb 2012, pp. 64-67(4)